



HMC476SC70 / 476SC70E

v04.0814

SIGE HBT GAIN BLOCK MMIC AMPLIFIER, DC - 6 GHz

Typical Applications

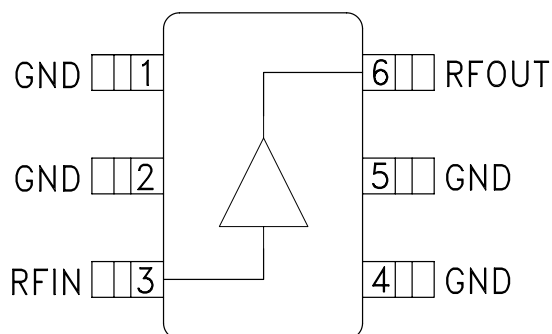
The HMC476SC70(E) is ideal for:

- Cellular / PCS / 3G
- WiBro / WiMAX / 4G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

Features

- P1dB Output Power: +12 dBm
- Gain: 20 dB
- Output IP3: +24 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +5V to +12V
- Industry Standard SC70 Package

Functional Diagram



General Description

The HMC476SC70(E) is a SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 6 GHz. This industry standard SC70 packaged amplifier can be used as a cascadable 50 Ohm RF/IF gain stage as well as a LO or PA driver with up to +12 dBm output power. The HMC476SC70(E) offers 20 dB of gain with a +24 dBm output IP3 at 850 MHz while requiring only 35 mA from a single positive supply. The Darlington topology results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

Electrical Specifications, $V_s = 5V$, $R_{bias} = 56 \text{ Ohm}$, $T_A = +25^\circ \text{ C}$

| Parameter | | Min. | Typ. | Max. | Units |
|---|---------------|------|-------|-------|--------|
| Gain | DC - 2.0 GHz | 16 | 19 | | dB |
| | 2.0 - 4.0 GHz | 13 | 16 | | dB |
| | 4.0 - 6.0 GHz | 9 | 12 | | dB |
| Gain Variation Over Temperature | DC - 6 GHz | | 0.008 | 0.012 | dB/ °C |
| Input Return Loss | DC - 4 GHz | | 20 | | dB |
| | 4.0 - 6.0 GHz | | 15 | | dB |
| Output Return Loss | DC - 4 GHz | | 20 | | dB |
| | 4.0 - 6.0 GHz | | 13 | | dB |
| Reverse Isolation | DC - 6 GHz | | 18 | | dB |
| Output Power for 1 dB Compression (P1dB) | 0.5 - 4.0 GHz | 9.0 | 12.0 | | dBm |
| | 4.0 - 6.0 GHz | 8.0 | 11.0 | | dBm |
| Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing) | 0.5 - 4.0 GHz | | 24 | | dBm |
| | 4.0 - 6.0 GHz | | 22 | | dBm |
| Noise Figure | 0.5 - 4.0 GHz | | 2.5 | | dB |
| | 4.0 - 6.0 GHz | | 3.0 | | dB |
| Supply Current (Icq) | | | 35 | 42 | mA |

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HMC476SC70* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC476SC70 Evaluation Board

TOOLS AND SIMULATIONS

- HMC476SC70 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: 6 Lead Plastic SC70 Package (QTR: 08002 REV: 01)
- Package/Assembly Qualification Test Report: Plastic Encapsulated 4-LEAD MICRO-P (QTR: 05007 REV: 01)
- Semiconductor Qualification Test Report: SiGe HBT-A (QTR: 2013-00227)

DESIGN RESOURCES

- HMC476SC70 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC476SC70 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

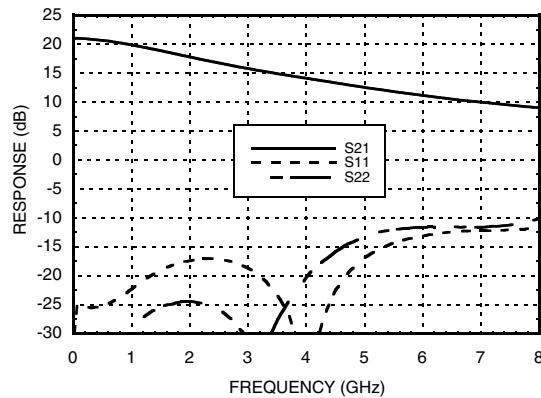
Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

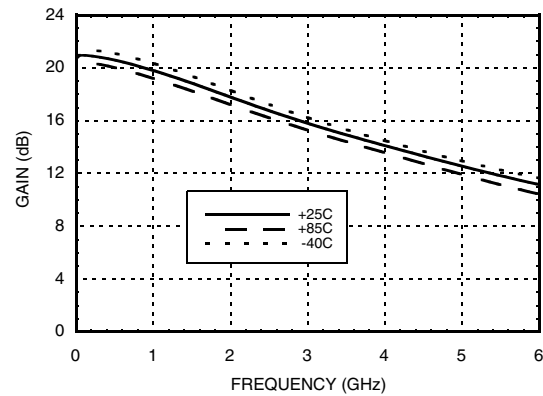
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**SIGE HBT GAIN BLOCK
MMIC AMPLIFIER, DC - 6 GHz**

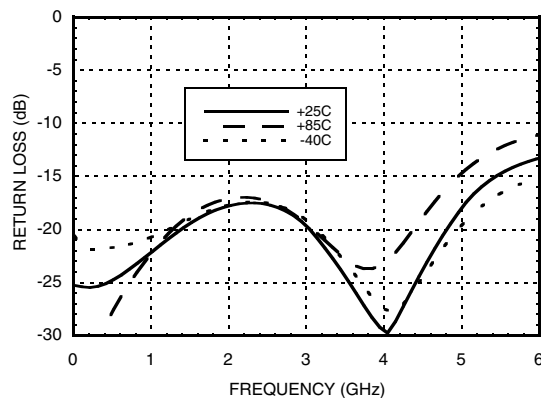
Broadband Gain & Return Loss



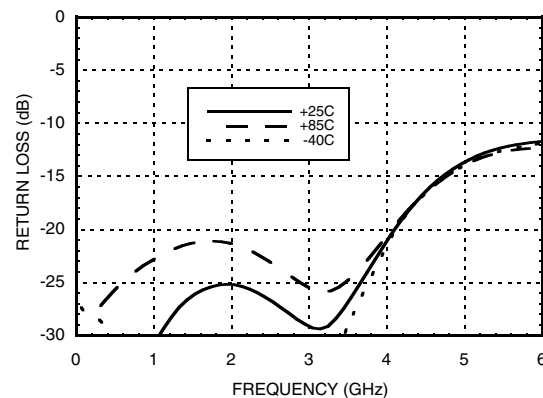
Gain vs. Temperature



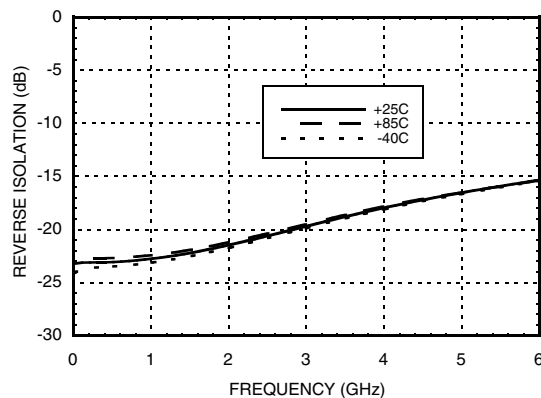
Input Return Loss vs. Temperature



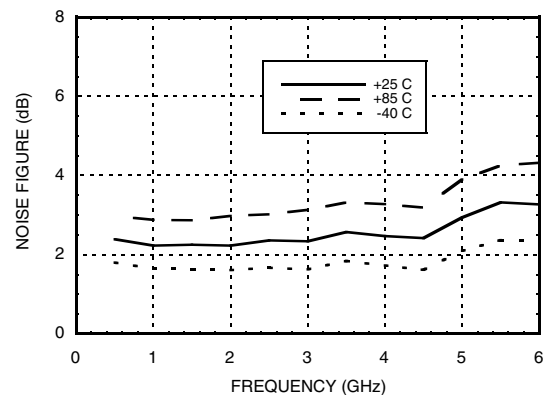
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



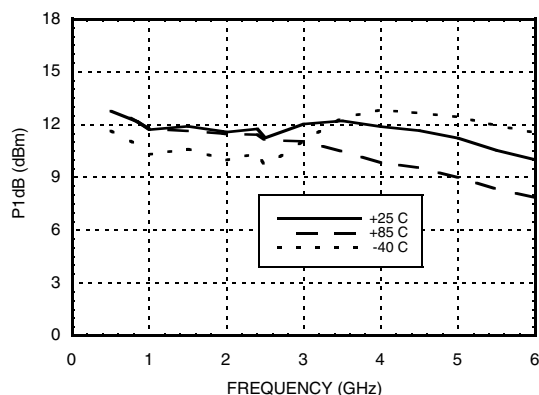


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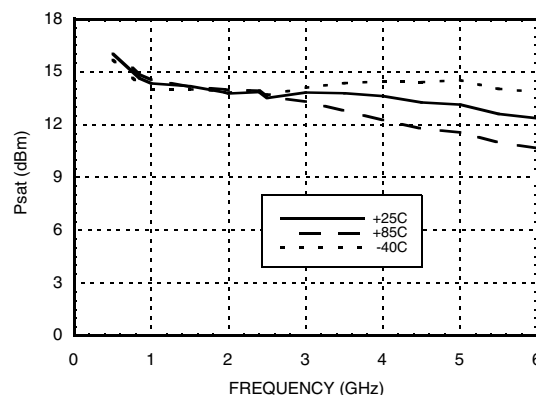
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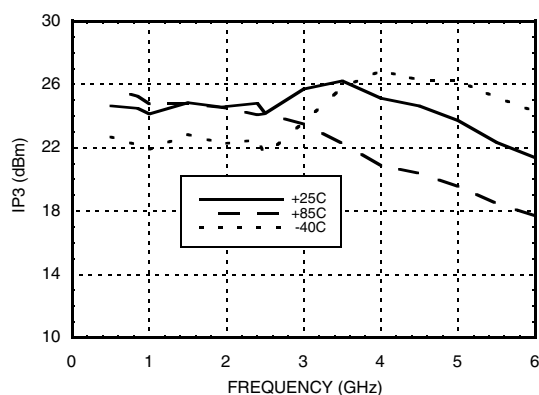
P1dB vs. Temperature



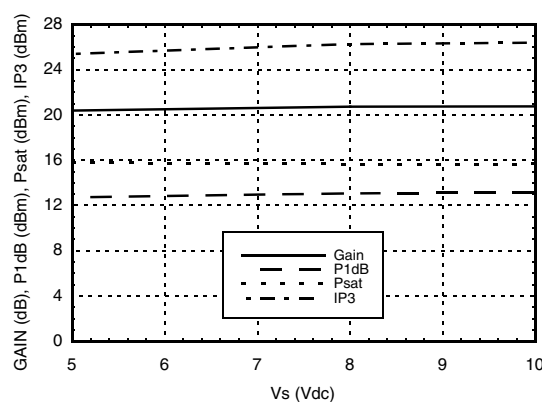
Psat vs. Temperature



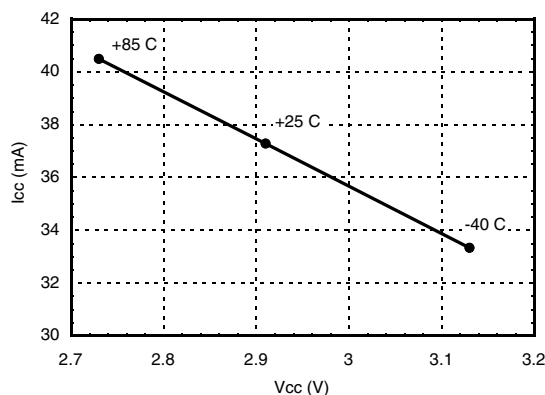
Output IP3 vs. Temperature



**Gain, Power & OIP3 vs. Supply Voltage
for Constant $I_{CC} = 35$ mA @ 850 MHz**



**I_{CC} vs. V_{CC} Over Temperature for
Fixed $V_S = 5$ V, $R_{BIAS} = 56$ Ohms**

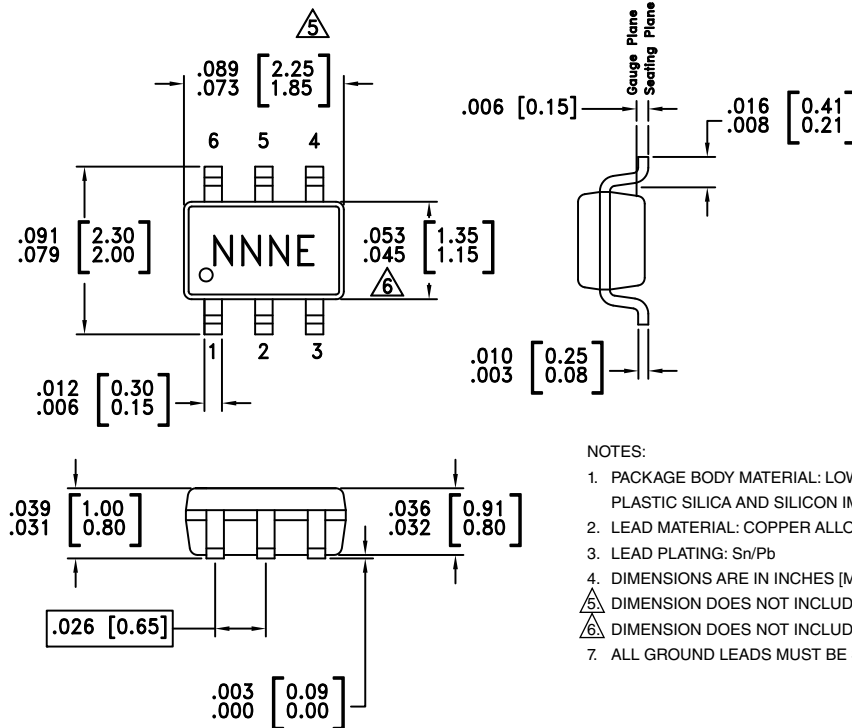


**SIGE HBT GAIN BLOCK
MMIC AMPLIFIER, DC - 6 GHz**
Absolute Maximum Ratings

| | |
|---|----------------|
| Collector Bias Voltage (Vcc) | +6V |
| Collector Bias Current (Icc) | 45 mA |
| RF Input Power (RFIN)(Vcc = +2.4V) | +5 dBm |
| Junction Temperature | 150 °C |
| Continuous P _{diss} (T = 85 °C) (derate 7.75 mW/°C above 85 °C) | 0.504 W |
| Thermal Resistance (junction to lead) | 129 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| ESD Sensitivity (HBM) | Class 1A |



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing

NOTES:

1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
2. LEAD MATERIAL: COPPER ALLOY
3. LEAD PLATING: Sn/Pb
4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
6. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking |
|-------------|--|---------------|---------------------|-----------------|
| HMC476SC70 | Low Stress Injection Molded Plastic | Sn/Pb | MSL1 ^[1] | 476E |
| HMC476SC70E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 ^[2] | 476E |

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

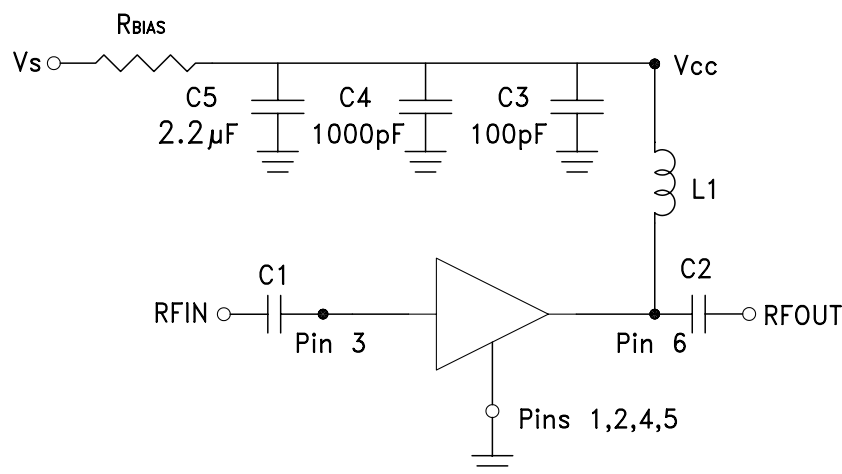
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Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|------------|----------|---|---------------------|
| 1, 2, 4, 5 | GND | These pins must be connected to RF/DC ground. | |
| 3 | RFIN | This pin is DC coupled. An off chip DC blocking capacitor is required. | |
| 6 | RFOUT | RF output and DC Bias (Vcc) for the output stage. | |

Application Circuit



Recommended Bias Resistor Values for $I_{CC} = 35 \text{ mA}$, $R_{BIAS} = (V_S - V_{CC}) / I_{CC}$

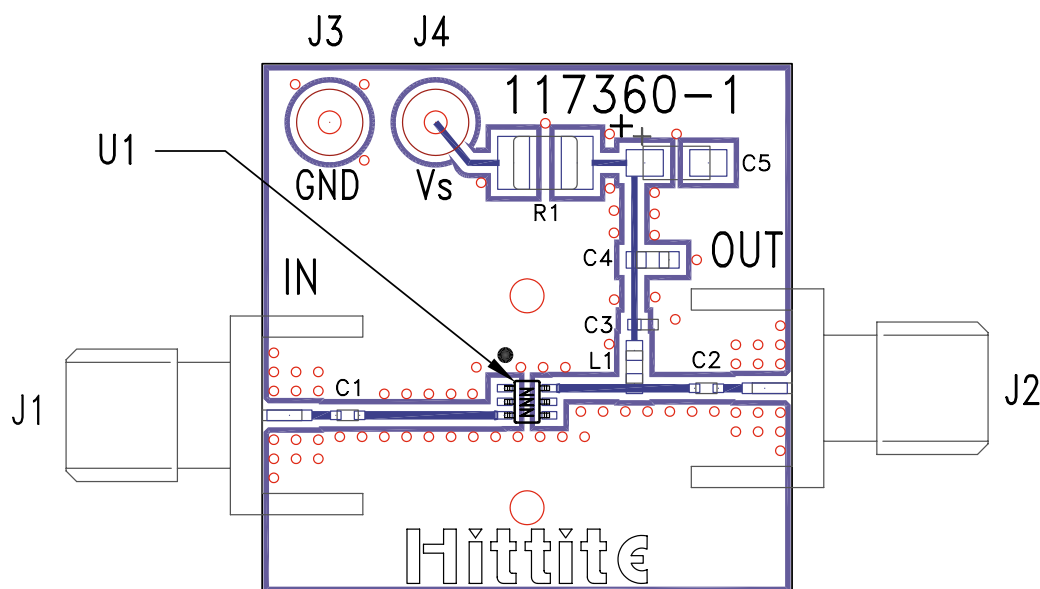
| Supply Voltage (Vs) | 5V | 8V | 10V | 12V |
|--------------------------------|-------|-------|-------|-------|
| R _{BIAS} VALUE | 56 Ω | 130 Ω | 180 Ω | 240 Ω |
| R _{BIAS} POWER RATING | 1/8 W | 1/4 W | 1/4 W | 1/2 W |

Note:

1. External blocking capacitors are required on RFIN and RFOUT.
2. R_{BIAS} provides DC bias stability over temperature.

Recommended Component Values for Key Application Frequencies

| Component | Frequency (MHz) | | | | | | | |
|-----------|-----------------|--------|--------|--------|--------|--------|--------|--------|
| | 50 | 900 | 1900 | 2200 | 2400 | 3500 | 5200 | 5800 |
| L1 | 270 nH | 56 nH | 18 nH | 18 nH | 15 nH | 8.2 nH | 6.8 nH | 3.3 nH |
| C1, C2 | 0.01 μF | 100 pF | 100 pF | 100 pF | 100 pF | 100 pF | 100 pF | 100 pF |

Evaluation PCB

List of Materials for Evaluation PCB 118038 [1]

| Item | Description |
|---------|---------------------------------|
| J1 - J2 | PCB Mount SMA Connector |
| J3 - J4 | DC Pin |
| C1 - C3 | 100 pF Capacitor, 0402 Pkg. |
| C4 | 1000 pF Capacitor, 0603 Pkg. |
| C5 | 2.2 μ F Capacitor, Tantalum |
| R1 | 50 Ohm Resistor, 1210 Pkg. |
| L1 | 18 nH Inductor, 0603 Pkg. |
| U1 | HMC476SC70(E) |
| PCB [2] | 117360 Evaluation PCB |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.